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View Online at https://aerobasegroup.com/nsn/5961-01-046-9559

Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.295 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

Between 1.00 amperes source cutoff current and 3.00 amperes source cutoff current

Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

80131-release6357 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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